

## AMENDMENTS TO THE CLAIMS

### Listing of Claims:

This listing of claims will replace all prior versions, and listings of claims in the application:

Claim 26 (currently amended): A method for removing polymer residues on sidewalls of metal lines, comprising:

    providing a wafer with at least a metal line layer formed thereon, the sidewalls of the metal lines of the metal line layer having polymer residues formed thereon;

    immersing said wafer in a stripping solution for removing the polymer residues in accordance with a first immersion time;

    removing said wafer from said stripping solution and maintaining placing said wafer over said stripping solution for a first time so that as to render said stripping solution left on said wafer drips dripping down;

    immersing said wafer in a first organic solvent for removing said stripping solution left on said wafer in accordance with a second immersion time;

    removing said wafer from said first organic solvent and maintaining placing said wafer over said stripping solution and said first organic solvent for a

~~second time at least 50 seconds so that as to render~~ said striping solution and said first organic solvent left on said wafer ~~drip~~ dripping down;

immersing said wafer in a water flow for removing the stripping solution and said first organic solvent left on said wafer in accordance with a third immersion time; and

removing water left on said wafer in accordance with a predetermined time.

Claim 27 (original): The method of claim 26, wherein said first immersion time is about 10 minutes.

Claim 28 (original): The method of claim 26, wherein said first time is about 100 seconds.

Claim 29 (original): The method of claim 26, wherein said second immersion time is about 5 minutes.

Claim 30 (original): The method of claim 26, wherein said second time is about 50 seconds.

Claim 31 (original): The method of claim 26, wherein said third immersion time is about 10 minutes.

Claim 32 (currently amended): The method of claim 26, wherein said predetermined time is about 10 minutes.

Claim 33 (original): The method of claim 26, wherein said stripping solution comprises alcohol amine, water, dihydroxylbenzene, hydroxyl amine and anticorrosion agent.

Claim 34 (original): The method of claim 26, wherein said first organic solvent comprises alcohol (ROH).

Claim 35 (currently amended): The method of claim 34, wherein said first alcohol solvent comprises is methanol.

Claim 36 (currently amended): The method of claim 34, wherein said first alcohol solvent comprises is isopropyl alcohol.

Claim 37 (currently amended): The method of claim 26, wherein prior to immersing said wafer in said water flow, further comprising immersing said wafer in a second organic solvent for further removing said stripping solution left on said wafer in accordance with a fourth immersion time, and removing said wafer from said second organic solvent and maintaining placing said wafer over said stripping solution, said first organic solvent and said second organic solvent for a third time at least 50 seconds so that as to render said stripping solution, said first organic solvent and said second organic solvent drip dripping down.

Claim 38 (original): The method of claim 37, wherein said fourth immersion time is about 5 minutes.

Claim 39 (original): The method of claim 37, wherein said third time is about 50 seconds.

Claim 40 (original): The method of claim 37, wherein said second organic solvent comprises alcohol (ROH).

Claim 41 (original): The method of claim 40, wherein said second organic solvent comprises methanol.

Claim 42 (original): The method of claim 40, wherein said second organic solvent comprises isopropyl alcohol.

Claim 43 (original): The method of claim 26, wherein further comprising providing an inert gas flow in said first organic solvent.

Claim 44 (original): The method of claim 43, wherein said inert gas flow comprises nitrogen gas flow.

Claim 45 (original): The method of claim 43, wherein the flow rate of said inert gas flow is about 15 liters/minute.

Claim 46 (original): The method of claim 44, wherein the flow rate of said nitrogen gas flow comprises 15 liters/minute.

Claim 47 (original): The method of claim 37, wherein further comprising providing an inert gas flow in said second organic solvent.

Claim 48 (original): The method of claim 47, wherein said inert gas flow comprises nitrogen gas flow.

Claim 49 (original): The method of claim 47, wherein the flow rate of said inert gas flow is about 15 liters/per minute.

Claim 50 (original): The method of claim 48, wherein the flow rate of said nitrogen gas flow is about 15 liters/per minute.

**AMENDMENTS TO THE DRAWINGS**

The attached replacement drawing sheet includes a change to FIG. 5A. This sheet, which includes FIG. 5A, replaces the original sheet including FIG. 5A. In FIG. 5A, the reference signs “502” which are originally described in the specification is added.

ATTACHMENT: One replacement sheet.